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SST39VF3201B

The SST39VF3201B device is a 2M x16 CMOS Multi- Purpose Flash Plus (MPF+) manufactured with SST's proprietary, high performance CMOS SuperFlash technology. The split-gate cell design and thick-oxide tunneling injector attain better reliability and manufacturability compared with alternate approaches. The SST39VF3201B writes (Program or Erase) with a 2.7-3.6V power supply. This device conforms to JEDEC standard pin assignments for x16 memories.

Type	Voltage	Density	Read Access Speed	Temperature Range
x16 MPF+	2.7-3.6	32 Mbit	70 ns	0 °C to +70 °C -40 °C to +85 °C

Product Documents: [Data Sheet: 32 Mbit \(x16\) Multi-Purpose Flash Plus](#)

Simulation Tools: [IBIS Model](#)
[SOMA](#)

Developer Support: [SST Programming Solutions](#)

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